

POWER SCHOTTKY RECTIFIERS

MAIN PRODUCT CHARACTERISTICS

$I_{F(AV)}$	1 A
V_{RRM}	20 V
$T_j(\text{max})$	150°C
$V_F(\text{max})$	0.41 V

FEATURES AND BENEFITS

- Very small conduction losses
- Negligible switching losses
- Extremely fast switching
- Low forward voltage drop for higher efficiency & extended battery life
- Low thermal resistance

DESCRIPTION

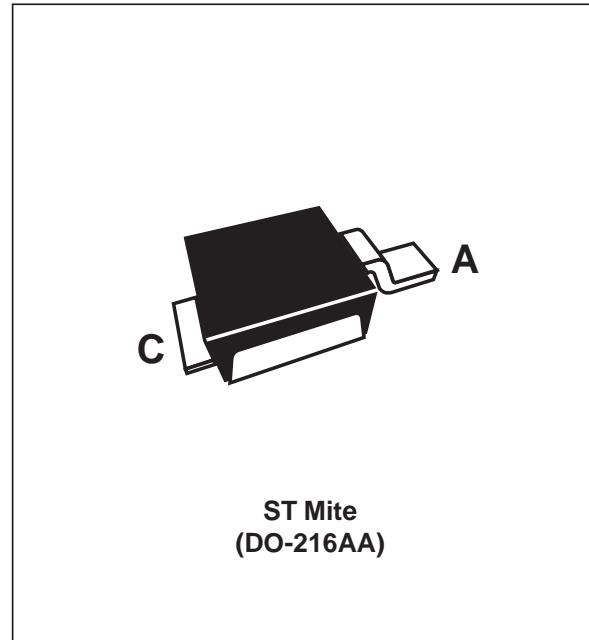
Single Schottky rectifier suited for switch mode power supplies and high frequency DC to DC converters.

Packaged in ST Mite, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications. Due to the small size of the package this device fits battery powered equipment (cellular, notebook, PDA's, printers) as well chargers and PCMCIA cards.

ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
V_{RRM}	Repetitive peak reverse voltage		20	V
$I_{F(\text{RMS})}$	RMS forward current		2	A
$I_{F(AV)}$	Average forward current	$T_c = 140^\circ\text{C}$ $\delta = 0.5$	1	A
I_{FSM}	Surge non repetitive forward current	$t_p = 8.3 \text{ ms sinusoidal}$	50	A
T_{stg}	Storage temperature range		- 65 to + 150	°C
T_j	Maximum operating junction temperature*		150	°C
dV/dt	Critical rate of rise of reverse voltage (rated V_r , $T_j = 25^\circ\text{C}$)		10000	V/ μ s

* : $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th}(j - a)}$ thermal runaway condition for a diode on its own heatsink



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THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
R _{th} (j-c)	Junction to case	20	°C/W
R _{th} (j-a)	Junction to ambient with minimum recommended pad size, PC board FR4	250	°C/W

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Tests conditions		Value			Unit
				Min.	Typ.	Max.	
I _R *	Reverse leakage current	T _j = 25°C	V _R = V _{RRM}		1.3	3.9	μA
		T _j = 100°C			275	850	
		T _j = 25°C	V _R = 10 V		0.6	2.0	
		T _j = 100°C			145	450	
		T _j = 25°C	V _R = 5 V		0.4	1.0	
		T _j = 100°C			105	300	
V _F *	Forward voltage drop	T _j = 25°C	I _F = 1 A		0.44	0.49	V
		T _j = 100°C			0.36	0.41	
		T _j = 25°C	I _F = 2 A		0.48	0.54	
		T _j = 100°C			0.42	0.48	

Pulse test : * tp ≤ 380 μs, δ ≤ 2%

To evaluate the conduction losses use the following equation :

$$P = 0.34 \times I_{F(AV)} + 0.07 I_{F^2(RMS)}$$

Fig. 1: Conduction losses versus average current.

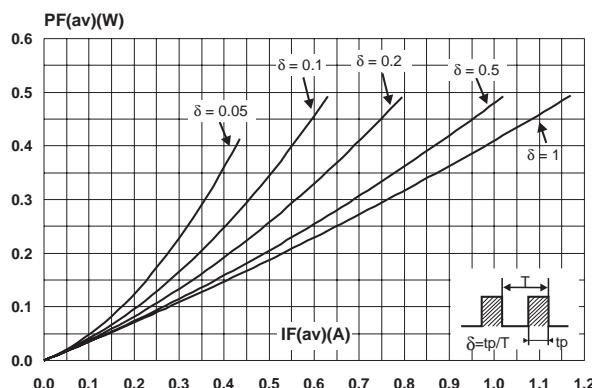


Fig. 3: Non repetitive surge peak forward current versus overload duration (maximum values).

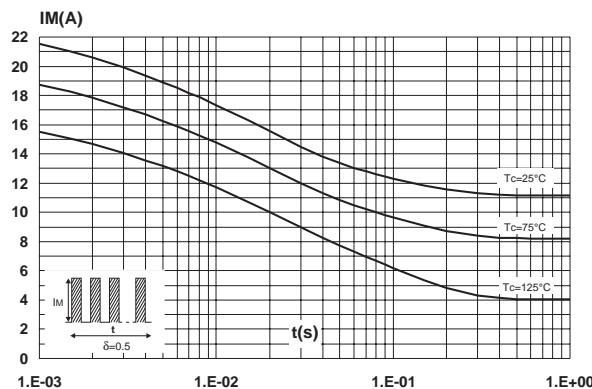


Fig. 5: Reverse leakage current versus reverse voltage applied (typical values).

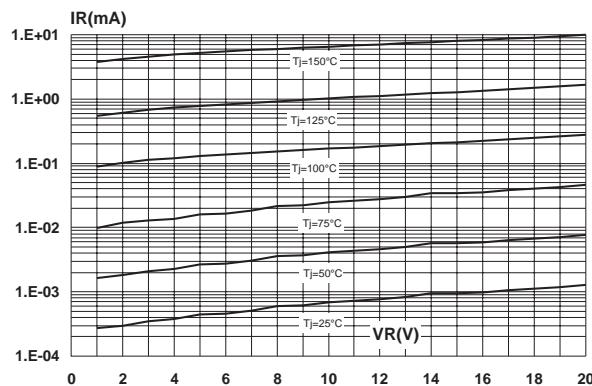


Fig. 2: Average forward current versus ambient temperature ($\delta = 0.5$)

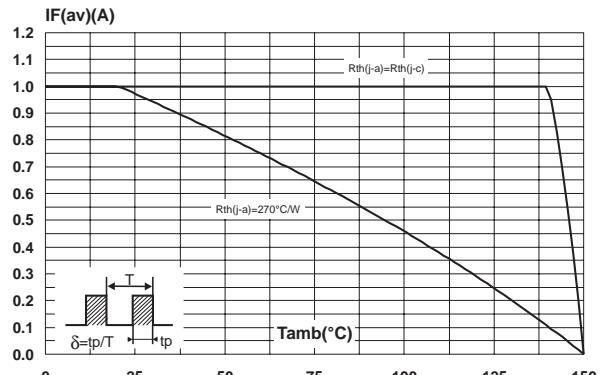


Fig. 4: Relative variation of thermal impedance junction to case versus pulse duration.

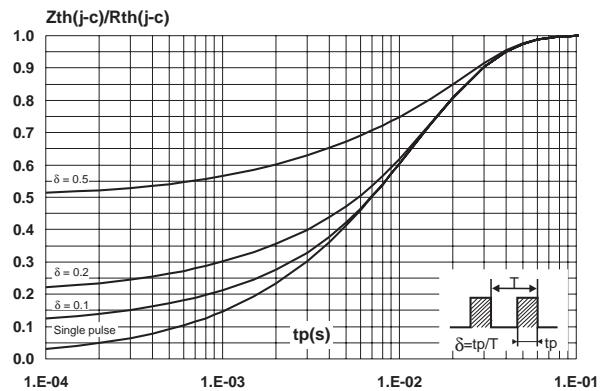
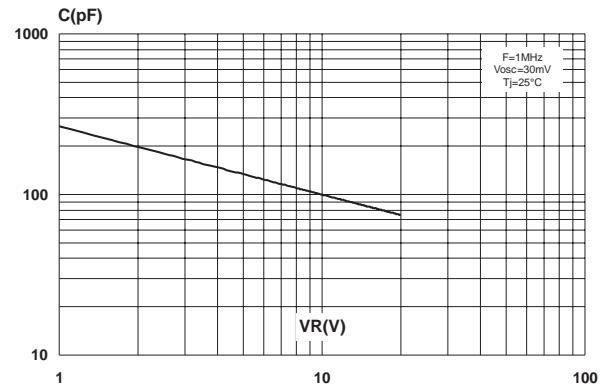


Fig. 6: Junction capacitance versus reverse voltage applied (typical values).



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Fig. 7-1: Forward voltage drop versus forward current (low level).

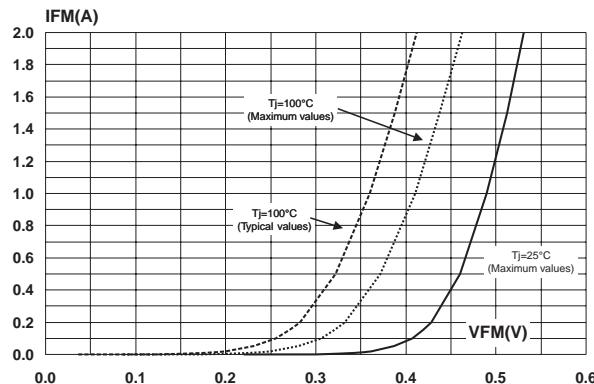


Fig. 7-2: Forward voltage drop versus forward current (high level)

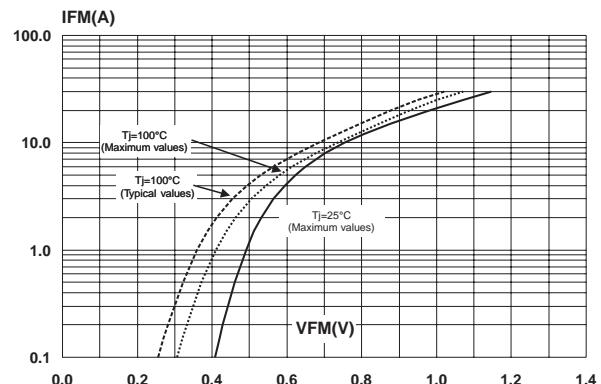
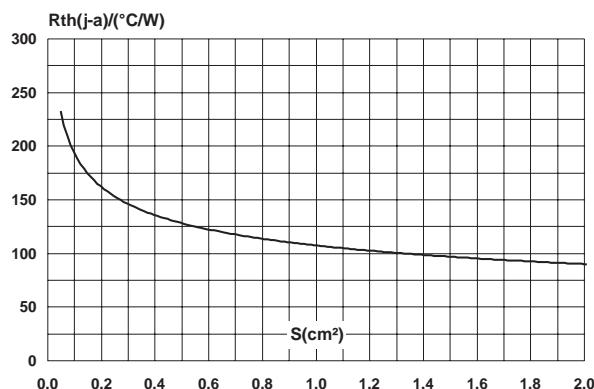


Fig. 8: Thermal resistance junction to ambient versus copper surface under tab (epoxy printed board FR4, Cu = 35μm).

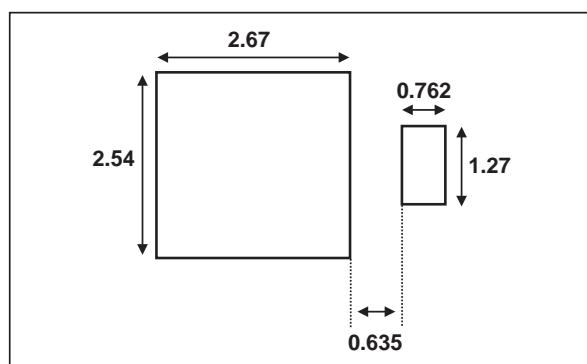


PACKAGE MECHANICAL DATA
ST Mite

REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.85	1.00	1.15	0.033	0.039	0.045
A1			0.10			0.004
b	0.40		0.65	0.016		0.025
b2	0.70			1.00	0.027	0.039
c	0.10			0.25	0.004	
D	1.75	1.90	2.05	0.069	0.007	0.081
E	1.75	1.90	2.05	0.069	0.007	0.081
H	3.60	3.75	3.90	0.142	0.148	0.154
L	0.50	0.63	0.80	0.047	0.025	0.031
L2	1.20	1.35	1.50	0.047	0.053	0.059
L3	0.50 ref (Typ.)			0.019 ref (Typ.)		
R	0.07			0.003		
R1	0.07			0.003		

Note: The anode is connected to the longer tab
The cathode is connected to the shorter tab (heatsink)

FOOTPRINT (dimensions in mm)



STPS120M

Type	Marking	Package	Weight	Base qty	Delivery mode
STPS120M	120	ST Mite	15.5 mg	12000	Tape & reel

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